

EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	353204	(light radiation) near10 emitt\$3	US-PGPU B; USPAT; USOCR	OR	ON	2007/03/02 15:28
L2	25096	1 and collector	US-PGPU B; USPAT; USOCR	OR	ON	2007/03/02 15:29
L3	16279	2 and emitter	US-PGPU B; USPAT; USOCR	OR	ON	2007/03/02 15:29
L4	3736	3 and (substrate wafer)	US-PGPU B; USPAT; USOCR	OR	ON	2007/03/02 14:30
L5	785	4 and (("PN" P-N "P and N") near5 junction)	US-PGPU B; USPAT; USOCR	OR	ON	2007/03/02 14:31
L6	616	5 and (insulat\$3 dielectric)	US-PGPU B; USPAT; USOCR	OR	ON	2007/03/02 15:29
L7	306199	(light radiation) same emitt\$3	FPRS; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2007/03/02 15:29
L8	2915	7 and collector	FPRS; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2007/03/02 16:25
L9	1792	8 and emitter	FPRS; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2007/03/02 15:29
L11	175	9 and (insulat\$3 dielectric)	FPRS; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2007/03/02 15:38

EAST Search History

L13	26370	(semiconductor near5 body)	US-PGPU B; USPAT; USOCR	OR	ON	2007/03/02 15:49
L14	2381	vertical near5 bipolar near5 transistor	US-PGPU B; USPAT; USOCR	OR	ON	2007/03/02 16:24
L15	345	13 and 14	US-PGPU B; USPAT; USOCR	OR	ON	2007/03/02 15:49
L16	322	15 and base	US-PGPU B; USPAT; USOCR	OR	ON	2007/03/02 15:50
L17	305	16 and collector	US-PGPU B; USPAT; USOCR	OR	ON	2007/03/02 15:50
L18	304	17 and emitter	US-PGPU B; USPAT; USOCR	OR	ON	2007/03/02 15:50
L19	66	18 and (light radiation)	US-PGPU B; USPAT; USOCR	OR	ON	2007/03/02 16:26
L20	643460	semiconductor	US-PGPU B; USPAT; USOCR	OR	ON	2007/03/02 16:24
L21	2232	20 and 14	US-PGPU B; USPAT; USOCR	OR	ON	2007/03/02 15:49
L22	2058	21 and base	US-PGPU B; USPAT; USOCR	OR	ON	2007/03/02 15:50
L23	1912	22 and collector	US-PGPU B; USPAT; USOCR	OR	ON	2007/03/02 15:50
L24	1856	23 and emitter	US-PGPU B; USPAT; USOCR	OR	ON	2007/03/02 15:50
L25	620	24 and (light radiation)	US-PGPU B; USPAT; USOCR	OR	ON	2007/03/02 15:51

EAST Search History

L26	1151871	semiconductor	FPRS; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2007/03/02 16:24
L28	754	26 and (vertical near5 bipolar near5 transistor)	FPRS; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2007/03/02 16:25
L29	406	28 and collector	FPRS; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2007/03/02 16:25
L30	485	28 and base	FPRS; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2007/03/02 16:25
L31	398	28 and emitter	FPRS; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2007/03/02 16:25
L32	286	29 and 30 and 31	FPRS; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2007/03/02 16:25
L33	7	32 and (light radiation)	FPRS; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2007/03/02 16:26